

STPS20SM80C

Power Schottky rectifier

Features

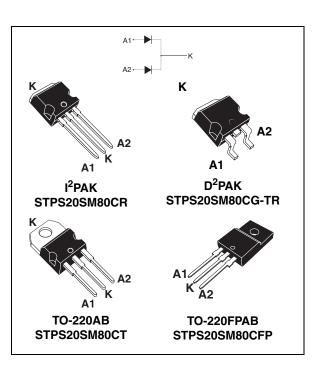
- High junction temperature capability
- Optimized trade-off between leakage current and forward voltage drop
- Low leakage current
- Avalanche capability specified
- Insulated package TO-220FPAB
 - insulated voltage: 2000 V
 - package capacitance: 45 pF

Description

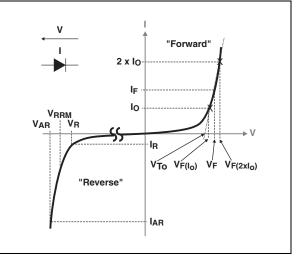
This dual diode Schottky rectifier is suited for high frequency switch mode power supply.

Packaged in TO-220AB, I²PAK, D²PAK and TO-220FPAB, this device is particularly suited for use in notebook, game station, LCD TV and desktop adapters, providing these applications with a good efficiency at both low and high load.

Symbol	Value
I _{F(AV)}	2 x 10 A
V _{RRM}	80 V
T _j (max)	175 °C
V _F (typ)	515 mV







a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 13*. V_{AR} and I_{AR} are pulse measurements (t_p < 1 µs). V_R, I_R, V_{RRM} and V_F, are static characteristics

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1 Characteristics

Table 2.Absolute ratings (limiting values, per diode, at T_{amb} = 25 °C unless
otherwise specified)

Symbol	Parameter					Unit
V _{RRM}	Repetitive peak reverse volt	tage			80	V
I _{F(RMS)}	Forward rms current				30	А
	Average forward current,	TO-220AB, I ² PAK, D ² PAK	T _c = 155 °C T _c = 150 °C	Per diode Per device	10 20	٨
I _{F(AV)}	$\delta = 0.5$	TO-220FPAB	$T_c = 130 \ ^\circ C$ $T_c = 100 \ ^\circ C$		10 20	A
I _{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal}$ $T_c = 25 \text{ °C}$			220	А
P _{ARM} ⁽¹⁾	Repetitive peak avalanche	power	$T_j = 25 \ ^\circ C, t_p$	= 1 µs	5400	W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs, T _j < 1	t _p < 1 μs, T _j < 150 °C, I _{AR} < 16.2 A			V
V _{ASM} ⁽²⁾	Maximum single pulse peak avalanche voltage	t _p < 1 μs, T _j < 150 °C, I _{AR} < 16.2 A			100	V
T _{stg}	Storage temperature range	age temperature range			-65 to +175	°C
Тj	Maximum operating junction	n temperature ⁽³⁾)		175	°C

 For temperature or pulse time duration deratings, please refer to figure 3 and 4. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

2. See Figure 13

3. $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3.Thermal parameters

Symbol	Parameter			Value	Unit
	TO-220AB		per diode	2.30	
Б		I ² PAK, D ² PAK	total	1.55	°C/W
R _{th(j-c)}			per diode	5.80	C/VV
		TU-220FPAD	total	4.65	
R _{th(c)}	Coupling	TO-220AB I ² PAK, D ² PAK	- -	0.80	°C/W
	TO-220FPAB			3.50	

When the two diodes 1 and 2 are used simultaneously:

 ΔT_{j} (diode 1) = P(diode 1) x R_{th(j-c)}(Per diode) + P(diode 2) x R_{th(c)}



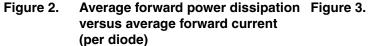
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
ا _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V - V	-	5.8	25	μA
'R` ′	$T_j = 125 \text{ °C}$	$T_j = 125 \degree C$ $V_R = V_{RRM}$	-	5	15	mA	
		T _j = 25 °C	1 - 5 4	-	0.590	0.640	
	²⁾ Forward voltage drop	T _j = 125 °C	I _F = 5 A	-	0.515	0.550	
Ve ⁽²⁾		T _j = 25 °C	I _F = 10 A	-	0.710	0.780	v
۷F		T _j = 125 °C	F = 10 A	-	0.595	0.650	v
		T _j = 25 °C	L = 20 A	-	0.850	0.945	
		T _i = 125 °C	I _F = 20 A	-	0.690	0.780	

Table 4. Static electrical characteristics (per diode)

1. Pulse test: t_p = 5 ms, δ < 2 %

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2 \ \%$

To evaluate the conduction losses use the following equation: P = 0.52 x $I_{F(AV)}$ + 0.013 x ${I_F}^2_{(RMS)}$



Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

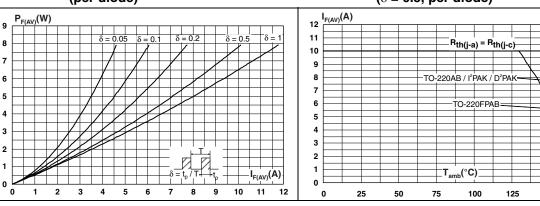
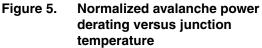
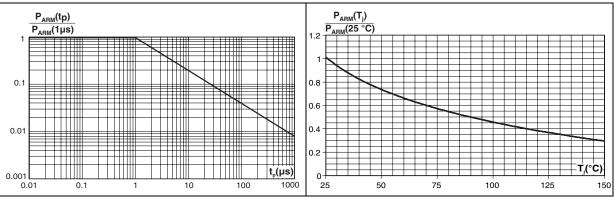


Figure 4. Normalized avalanche power derating versus pulse duration



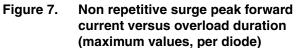


57

150

175

Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)



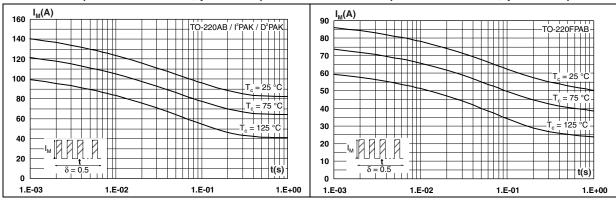
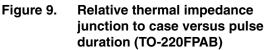
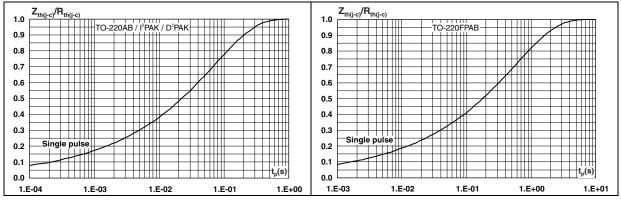


Figure 8. Relative thermal impedance junction to case versus pulse duration





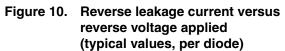
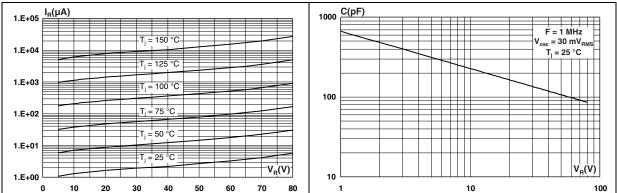


Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)





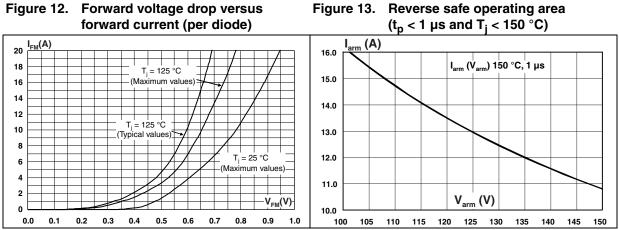
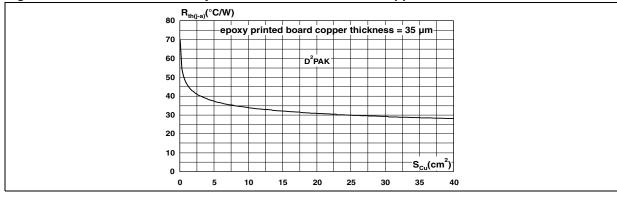


Figure 14. Thermal resistance junction to ambient versus copper surface under tab for D²PAK



2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB dimensions

			Dimer	nsions	
	Ref.	Millin	neters	Inc	hes
		Min.	Max.	Min.	Max.
	А	4.40	4.60	0.173	0.181
	С	1.23	1.32	0.048	0.051
H2 A Dia C.	D	2.40	2.72	0.094	0.107
	E	0.49	0.70	0.019	0.027
	F	0.61	0.88	0.024	0.034
	F1	1.14	1.70	0.044	0.066
	F2	1.14	1.70	0.044	0.066
	G	4.95	5.15	0.194	0.202
$ \downarrow F1 \rightarrow \downarrow $	G1	2.40	2.70	0.094	0.106
	H2	10	10.40	0.393	0.409
F→ ←	L2	16.4	Тур.	0.645	5 Тур.
	L4	13	14	0.511	0.551
	L5	2.65	2.95	0.104	0.116
G	L6	15.25	15.75	0.600	0.620
	L7	6.20	6.60	0.244	0.259
	L9	3.50	3.93	0.137	0.154
	М	2.6	Тур.	0.102	2 Тур.
	Dia.	3.75	3.85	0.147	0.151



			Dimer	nsions	
	Ref.	Millin	neters	Inc	hes
		Min.	Max.	Min.	Max.
	Α	4.4	4.9	0.173	0.192
	В	2.5	2.9	0.098	0.114
	D	2.45	2.75	0.096	0.108
	Е	0.4	0.7	0.016	0.028
	F	0.6	1	0.024	0.039
	F1	1.15	1.7	0.045	0.067
	F2	1.15	1.7	0.045	0.067
	G	4.95	5.2	0.195	0.205
	G1	2.4	2.7	0.094	0.106
	Н	10	10.7	0.394	0.421
	L2	16	Тур.	0.630) Тур.
	L3	28.6	30.6	1.126	1.205
G	L4	9.8	10.7	0.386	0.421
	L6	15.8	16.4	0.622	0.646
	L7	9	9.9	0.354	0.390
	Dia.	2.9	3.5	0.114	0.138

Table 6. TO-220FPAB dimensions



			Dimer	nsions	
	Ref.	Millin	neters	Inc	hes
		Min.	Max.	Min.	Max.
	А	4.40	4.60	0.173	0.181
	A1	2.49	2.69	0.098	0.106
$\begin{array}{c c} L2 \\ \hline \\ $	A2	0.03	0.23	0.001	0.009
	В	0.70	0.93	0.027	0.037
	• • B2	1.14	1.70	0.045	0.067
	C	0.45	0.60	0.017	0.024
	C2	1.23	1.36	0.048	0.054
$ \begin{array}{c} B2 \\ \hline B \\ \hline B \\ \hline \end{array} \end{array} $	D	8.95	9.35	0.352	0.368
G	E	10.00	10.40	0.393	0.409
A2	G	4.88	5.28	0.192	0.208
	L	15.00	15.85	0.590	0.624
M (*)	V2 L2	1.27	1.40	0.050	0.055
* FLAT ZONE NO LESS	L3	1.40	1.75	0.055	0.069
	M	2.40	3.20	0.094	0.126
	R	0.40	typ.	0.01	6 typ.
	V2	0°	8°	0°	8°





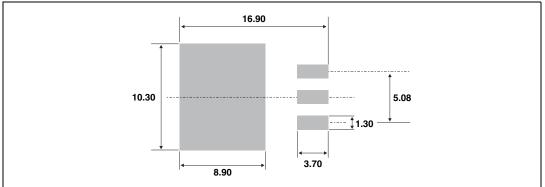


Table 6. I FAR differis				Dimer	sions				
				Ref.	Millin	neters	Inc	hes	
i			Min.	Max.	Min.	Max.			
		А	4.40	4.60	0.173	0.181			
		A1	2.40	2.72	0.094	0.107			
		b	0.61	0.88	0.024	0.035			
	D	b1	1.14	1.70	0.044	0.067			
		С	0.49	0.70	0.019	0.028			
		c2	1.23	1.32	0.048	0.052			
		D	8.95	9.35	0.352	0.368			
		е	2.40	2.70	0.094	0.106			
		e1	4.95	5.15	0.195	0.203			
	→ C	E	10	10.40	0.394	0.409			
l e1 →		L	13	14	0.512	0.551			
		L1	3.50	3.93	0.138	0.155			
		L2	1.27	1.40	0.050	0.055			

Table 8.I²PAK dimensions



3 Ordering information

Table 9.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20SM80CT	PS20SM80CT	TO-220AB	1.9 g	50	Tube
STPS20SM80CFP	PS20SM80CFP	TO-220FPAB	2.0 g	50	Tube
STPS20SM80CR	PS20SM80CR	I ² PAK	1.49 g	50	Tube
STPS20SM80CG-TR	PS20SM80CG	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 10.	Revision	history
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Date	Revision	Changes
11-Apr-2011	1	First issue.



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